

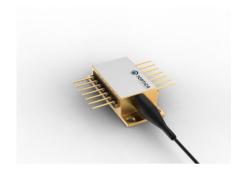
Revision 0.90

2025-04-08

## SINGLE FREQUENCY LASER DFB Laser



General Product Information	
Product	Application
Tunable 760 nm DFB Laser	Yb Spectroscopy
with hermetic 14-Pin Butterfly Housing (RoHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	
with PM Fiber, integrated $\mu\text{-}lsolator$ and Angled Physical Contact (APC)	



Absolute Maximum Ratings					
Parameter	Symbol	Unit	min	typ	max
Storage Temperature	Ts	°C	-40		85
Operational Temperature at Case	$T_C$	°C	-15		70
Operational Temperature at Chip	$T_{chip}$	°C	0		50
Forward Current	$I_{F}$	mA			180
Reverse Voltage	$V_{R}$	V			2
Output Power	$P_{\text{opt}}$	mW			14
TEC Current	$I_{TEC}$	Α			1.4
TEC Voltage	$V_{\text{TEC}}$	V			4.8

Measurement Conditions / Comments
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Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Symbol	Unit	min	typ	max
T <sub>case</sub>	°C	5		50
$T_{chip}$	°C	0		35
I <sub>F</sub>	mA			170
P <sub>opt</sub>	mW	4		12
	$T_{case}$ $T_{chip}$ $I_{F}$	$T_{case}$ °C $T_{chip}$ °C $I_F$ mA	$T_{case}$ °C 5 $T_{chip}$ °C 0 $I_F$ mA	$T_{case}$ °C 5 $T_{chip}$ °C 0 $I_F$ mA

Measurement Conditions / Comments
ex fiber



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Characteristics	Tchip = 25 °C at Bo	OL			
Parameter	Symbol	Unit	min	typ	max
Center Wavelength	$\lambda_{\text{C}}$	nm	759	760	761
Target Wavelength	$\lambda_{\mathrm{T}}$	nm		760.1	
Linewidth	Δλ	MHz		1	
Mode-hop free Tuning Range	$\Delta \lambda_{tune}$	pm	40		
Sidemode Suppression Ratio	SMSR	dB	30	45	
Temp. Coefficient of Wavelength	dλ / dT	nm/K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm/mA		0.002	
Laser Current	I <sub>LD</sub>	mA			170
Slope Efficiency	η	mW/mA		0.1	
Threshold Current	I <sub>th</sub>	mA			70
Polarization Extinction Ratio	PER	dB		20	

Measurement Conditions / Comments
reached between 10 and 40 °C at Popt = 12 mW
Popt = 12 mW
at target wawevelength
Popt = 12 mW
Popt = 12 mW
Popt = 12 mW

Monitor Diode				
Parameter	Symbol Unit	min	typ	max
Monitor Detector Responsivity	I <sub>mon</sub> / P <sub>or</sub> μΑ/m <sup>1</sup>	W 10		800

Measurement Conditions / Comments
5 V

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I <sub>TEC</sub>	Α		0.4	
Voltage	$U_TEC$	V		1.5	
Power Dissipation (total loss at case)	P <sub>loss</sub>	W		0.5	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments
Popt = 12 mW, ΔT = 30 K
Popt = 12 mW, ΔT = 30 K
Popt = 12 mW, ΔT = 30 K
Popt = 12 mW, ΔT =  Tcase - Tchip

Thermistor (Standard NTC Type)					
Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	b			3892	
Steinhart & Hart Coefficient A	А		1.	1293 x 10	-3
Steinhart & Hart Coefficient B	В		2.	3410 x 10	-4
Steinhart & Hart Coefficient C	С		8.	7755 x 10	-8

Measurement Conditions / Comments
Tchip = 25 °C
$R_1/R_2 = e^{\beta}(1/T_1 - 1/T_2)$ at Tchip = 0 50 °C

D-12489 Berlin

GERMANY



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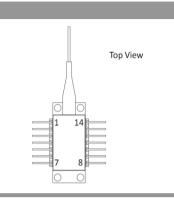
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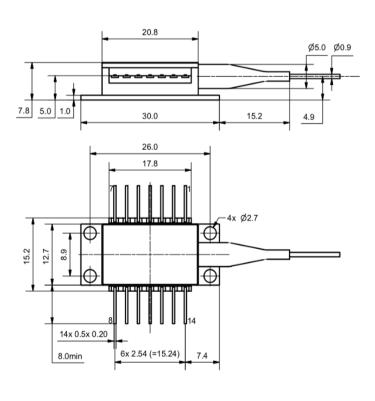


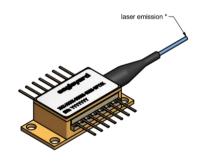
### Pin Assignment

1 Thermoelectric Cooler (+)	14 Thermoelectric Cooler (-)
2 Thermistor	13 Case
3 Photo Diode Anode	12 not connected
4 Photo Diode Cathode	11 Laser Diode Cathode
5 Thermistor	10 Laser Diode Anode
6 not connected	9 not connected
7 not connected	8 not connected



#### Package Drawings





AIZ-16-0222-1415



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## SINGLE FREQUENCY LASER DFB Laser



ns / Comments

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## SINGLE FREQUENCY LASER DFB Laser



#### Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



INVISIBLE LASER RADIATION
AVOID EYE OR SKIN EXPOSUR
TO DIRECT OR SCATTERED RADIATION
CLASS 4 LASER PRODUCT
WAVELENGTH 760 nm
MAX. OUTPUT POWER 14 mW

IEC-60825-

A laser diode is sensitive against optical feedback, so an optical isolator may be required in order to avoid any disturbance of the emission spectrum. Operating at moderate temperatures on proper heat sinks will contribute to a long lifetime of the diode.

Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.





Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

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